NSN 5961-01-111-5660

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-111-5660 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.0 emitter to base voltage, dc and 400.0 collector to base voltage/static/emitter open and 400.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 350.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No